## 國立成功大學 112學年度碩士班招生考試試題

編 號: 130

系 所:系統及船舶機電工程學系

科 目:電子學

日期:0206

節 次:第2節

備 註:可使用計算機

編號: 130

## 國立成功大學 112 學年度碩士班招生考試試題

系 所:系統及船舶機電工程學系

考試科目: 包3/图

考試日期:0206,節次:2

第1頁,共2頁

※ 考生請注意:本試題可使用計算機。 請於答案卷(卡)作答,於本試題紙上作答者,不予計分。

1. Use two ideal op amps and resistors to implement the summing function  $v_0 = v_1 + 2v_2 - 3v_3 - 5v_4$  (20%)

- 2. As Figure 1, derive the transfer function and show that the high-frequency gain is  $(-R_2/R_1)$  and the 3-dB frequency  $\omega_0=1/CR_1$ . Design the circuit to obtain a high-frequency input resistance of  $1k\Omega$ , a high-frequency gain of 40 dB, and a 3-dB frequency of 2 kHz. At what frequency does the magnitude of the transfer function reduce to unity? (20%)
- 3. In the circuit of Figure 2, the BJT is biased with a constant-current source, and  $v_{\text{sig}}$  is a small sine-wave signal. Find  $R_{\text{in}}$  and the gain  $v_o/v_{\text{sig}}$ . Assume  $\beta=100$ . If the amplitude of the signal  $v_{be}$  is to be limited to 5 mV, what is the largest signal at the input? What is the corresponding signal at the output? (20%)

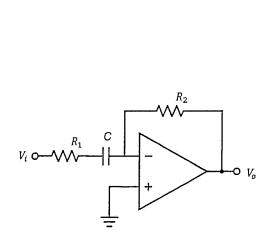


Figure 1

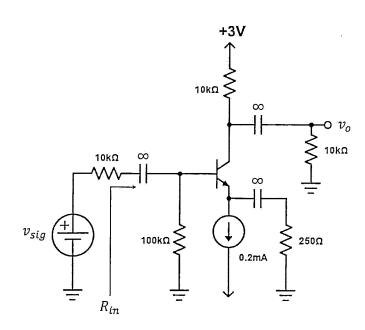


Figure 2

## 編號: /30

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考試科目:包子图

第2頁,共2頁

考試日期:0206,節次:2

4. Transistor  $Q_1$  in Figure 3 is operating as a CE amplifier with an active load provided by transistor  $Q_2$ , which is the output transistor in a current mirror formed by  $Q_2$  and  $Q_3$ . (Note that the biasing arrangement for  $Q_1$  is *not* shown.)

(a) Neglecting the finite base currents of  $Q_2$  and  $Q_3$ , and assuming that their  $V_{BE} \cong 0.7 \text{V}$  and that  $Q_2$  has five times the area of  $Q_3$ , find the value of I. (5%)

(b) If  $Q_1$  and  $Q_2$  are specified to have  $|V_A| = 20 \text{ V}$ , find  $r_{o1}$  and  $r_{o2}$  and hence the total resistance at the collector of  $Q_1$ . (5%)

(c) Find  $r_{\pi 1}$  and  $g_{m1}$  assuming that  $\beta_1 = 50$ . (5%)

(d) Find  $R_{in}$ ,  $A_{\nu}$ , and  $R_o$ . (5%)

5. The amplifier in Figure 4 is biased to operate at  $g_m$ = 5mA/V, and has the following component values:  $R_{sig}$ = 100 k $\Omega$ ,  $R_{GI}$ = 47M $\Omega$ ,  $R_{G2}$ = 10M $\Omega$ ,  $C_{CI}$ = 0.01 $\mu$ F,  $R_S$ = 2 k $\Omega$ ,  $C_S$ = 10 $\mu$ F,  $R_D$ = 4.7k $\Omega$ ,  $R_L$ = 10k $\Omega$ , and  $C_{C2}$ = 1 $\mu$ F. Find  $A_M$ ,  $f_{P1}$ ,  $f_{P2}$ ,  $f_Z$ ,  $f_{P3}$ , and  $f_L$ . (20%)

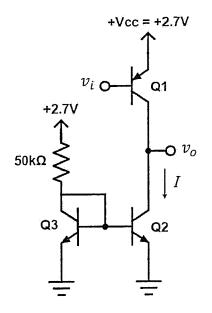


Figure 3

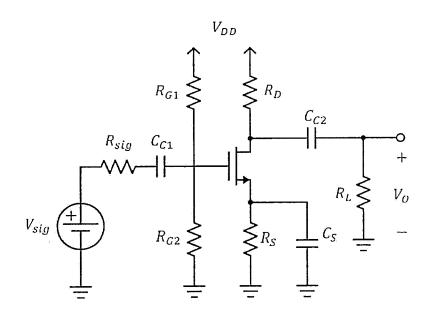


Figure 4